

# 2SC4278

# Transistor, NPN

## Features

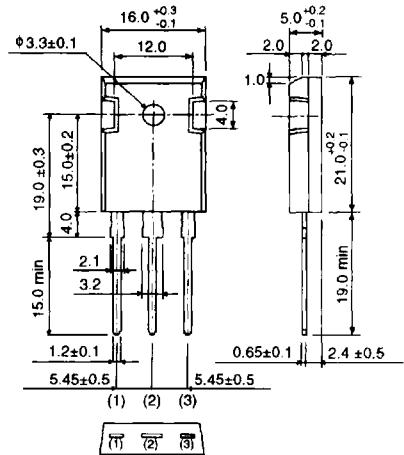
- available in TO-247 package
- high collector breakdown voltage, typically  $BV_{CEO} = 150\text{ V}$
- low collector saturation voltage, typically  $V_{CE(sat)} = 0.3\text{ V}$  at  $I_C/I_B = 7\text{ A}/0.7\text{ A}$
- large collector power dissipation  $P_C = 100\text{ W}$  at  $T_C = 25^\circ\text{C}$
- wide safe operating area (SOA)
- complementary pair with 2SA1633

## Applications

- low frequency power amplifier

## Dimensions (Units : mm)

2SC4278 (TO-247)



- (1) Base  
(2) Collector  
(3) Emitter

## Absolute maximum ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Limits	Unit	Conditions
Collector-to-base voltage	$V_{CBO}$	150	V	
Collector-to-emitter voltage	$V_{CEO}$	150	V	
Emitter-to-base voltage	$V_{EBO}$	5	V	
Collector current	$I_C$	10	A	Continuous (dc)
		20	A	Single pulse, $P_W = 100\text{ ms}$
Collector dissipation	$P_C$	100	W	$T_C = 25^\circ\text{C}$
Junction temperature	$T_j$	150	$^\circ\text{C}$	
Storage temperature	$T_{slg}$	-55 ~ +150	$^\circ\text{C}$	

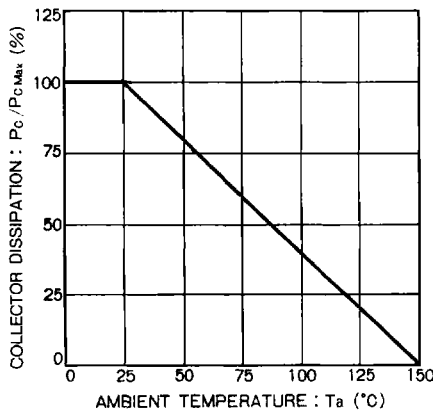
**Electrical characteristics (unless otherwise noted,  $T_a = 25^\circ\text{C}$ )**

Parameter	Symbol	Min	Typical	Max	Unit	Conditions
Collector-to-base breakdown voltage	$BV_{CBO}$	150			V	$I_C = 50 \mu\text{A}$
Collector-to-emitter breakdown voltage	$BV_{CEO}$	150			V	$I_C = 50 \text{mA}$
Emitter-to-base breakdown voltage	$BV_{EBO}$	5			V	$I_E = 50 \mu\text{A}$
Collector cutoff current	$I_{CBO}$			5	$\mu\text{A}$	$V_{CB} = 150 \text{V}$
Emitter cutoff current	$I_{EBO}$			5	$\mu\text{A}$	$V_{EB} = 5 \text{V}$
DC current gain	$h_{FE1}$	60		320		$V_{CE} = 5 \text{V}, I_C = 1 \text{A}, \text{single pulse}$
	$h_{FE2}$	35				$V_{CE} = 5 \text{V}, I_C = 5 \text{A}, \text{single pulse}$
Collector-to-emitter saturation voltage	$V_{CE(sat)}$		0.3	1.0	V	$I_C/I_B = 7 \text{A}/0.7 \text{A}, \text{single pulse}$
Base-to-emitter voltage	$V_{BE}$		0.95	1.5	V	$V_{CE} = 5 \text{V}, I_C = 5 \text{A}, \text{single pulse}$
Transition frequency	$f_T$		20		MHz	$V_{CE} = 5 \text{V}, I_E = -1 \text{A}, f = 10 \text{MHz}, \text{single pulse}$
Output capacitance	$C_{ob}$		200		pF	$V_{CB} = 10 \text{V}, I_E = 0 \text{A}, f = 1 \text{MHz}$

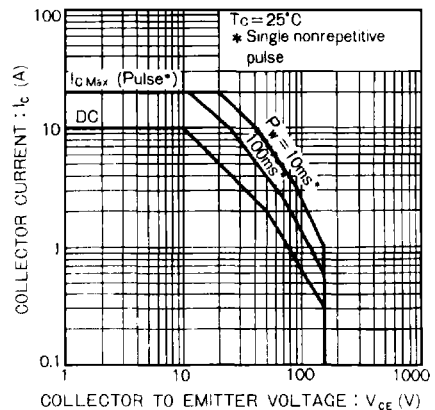
**$h_{FE}$  rankings**

Item	D	E	F
$h_{FE}$	60 ~ 120	100 ~ 120	160 ~ 320

**Electrical characteristic curves**



**Figure 1**



**Figure 2**

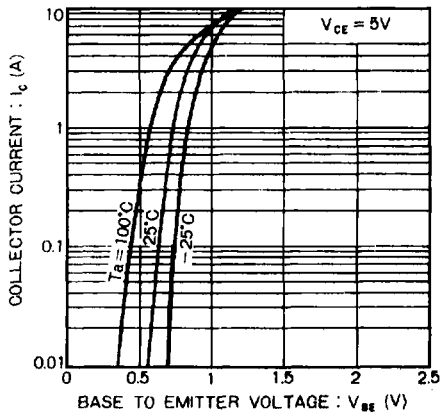


Figure 3

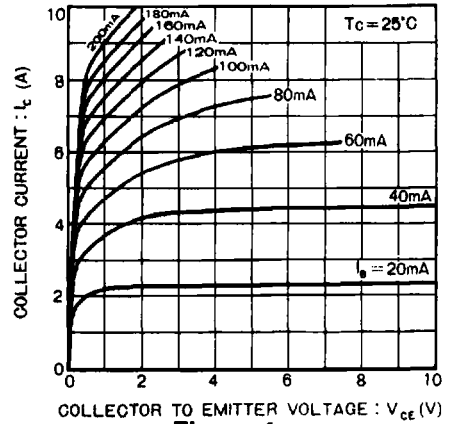


Figure 4

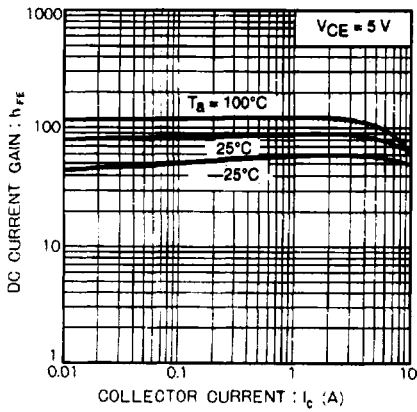


Figure 5

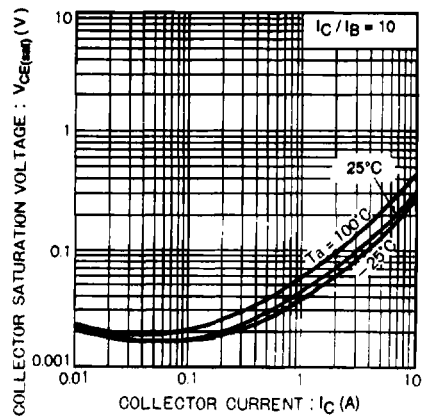


Figure 6

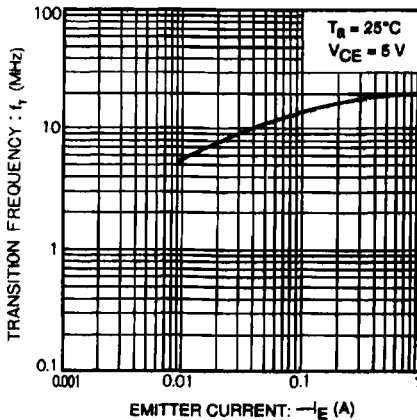


Figure 7

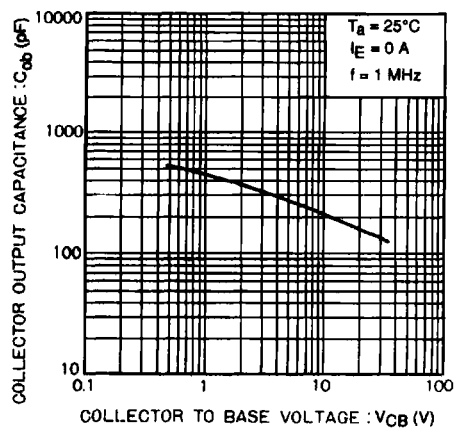


Figure 8

**Ordering information**

Package	Bulk
Code	
Basic order quantity	500
2SC4278	☆
★ = Standard, ☆ = Semi-standard, * = Special order	